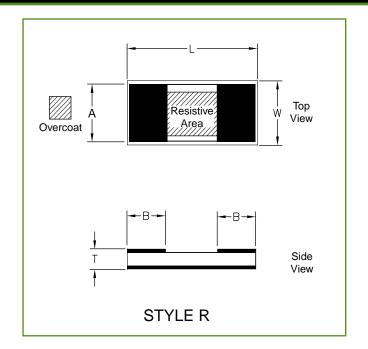
Chip Resistors Style CR

General Specifications

- **Resistance**: 50 and 100 Ω standard. 10 to 200 Ω available.
- Resistive Tolerance: ±5% Standard (2% Available).
- Operating Temp Range: -55 to +150°C
- Temperature Coefficient: ±150 ppm/°C
- Resistive Elements: Proprietary film.
- Substrate Material: Aluminum Nitride.
- Terminals: Silver
- Reliability: MIL-PRF-55342

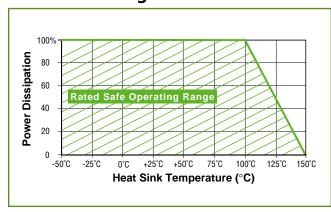


ATC Part Number	W	L	Т	Α	В	Capacitance	Power Max*
	±.010	±.010	±.005	±.005	±.005	(pF)	(Watts)
CR11005T0100J	.050	.100	.025	.045	.020	.75	5
CR11206T0100J	.060	.120	.025	.055	.020	.90	15
CR12010T0100J	.100	.200	.040	.090	.020	1.0	30
CR12525T0100J	.245	.245	.040	.130	.020	2.0	60
CR13725T0100J	.250	.375	.040	.198	.020	4.15	150
CR13737T0100J	.370	.370	.040	.330	.020	6.0	250

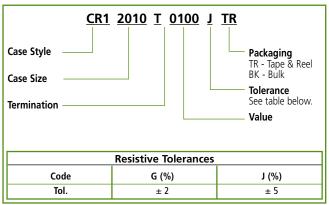
^{*} Test Condition: Chip soldered to a large copper carrier whose surface is at 100°C; maximum rated power applied.

Specification: The resistance of the film shall change no more than 0.5% during and after a 1000-hr. Burn-in per Mil-PRF-55342

Power Derating



ATC Part Number Code



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AMERICAN TECHNICAL CERAMICS

COMPONENT AND CUSTOM INTEGRATED PACKAGING SOLUTIONS FOR RF, MICROWAVE AND TELECOMMUNICATIONS